

SN3A - SN3M

PRV : 50 - 1000 Volts lo : 3.0 Amperes

FEATURES :

- * High current capability
- * High surge current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop
- * Pb / RoHS Free

MECHANICAL DATA:

- * Case : SMC Molded plastic
- * Epoxy : UL94V-O rate flame retardant
- * Lead : Lead Formed for Surface Mount
- * Polarity : Color band denotes cathode end
- * Mounting position : Any
- * Weight : 0.26 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

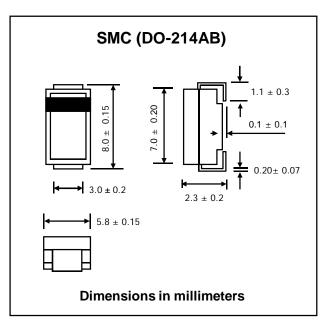
Rating at 25 °C ambient temperature unless otherwise specifie. Single phase, half wave, 60 Hz, resistive or inductive loac For capacitive load, derate current by 20%

RATING	SYMBOL	SN3A	SN3B	SN3D	SN3G	SN3J	SN3K	SN3M	UNITS
Maximum Repetitive Peak Reverse Voltage	Vrrm	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	Vrms	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Current Ta = 75 °C	lf	3.0						А	
Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on rated load (JEDEC Method)	Ігѕм	200						A	
Maximum Forward Voltage at IF = 3.0 Amps.	VF	1.0						V	
Maximum DC Reverse Current Ta = 25 °C	IR	5.0						μA	
at rated DC Blocking Voltage Ta = 100 °C	IR(H)	50						μA	
Typical Junction Capacitance (Note1)	Сл		50						pF
Junction Temperature Range	TJ		- 65 to + 150						°C
Storage Temperature Range	Тѕтс	- 65 to + 150						°C	

Notes :

(1) Measured at 1.0 MHz and applied reverse voltage of .0VDc

SURFACE MOUNT RECTIFIERS





RATING AND CHARACTERISTIC CURVES (SN3A - SN3M) FIG.1 - DERATING CURVE FOR OUTPUT FIG.2 - MAXIMUM NON-REPETITIVE PEAK **RECTIFIED CURRENT** FORWARD SURGE CURRENT 3.0 250 AVERAGE FORWARD OUTPUT PEAK FORWARD SURGE CURRENT, AMPERES T₁ = 105 °C CURRENT, AMPERES 2.4 200 1.8 150 1.2 100 8.3ms SINGLE HALF SINE-WAVI 50 0.6 (JEDEC) Method 0 0 1 0 25 50 75 100 125 150 175 2 4 6 10 20 40 60 100 AMBIENT TEMPERATURE, (°C) NUMBER OF CYCLES AT 60Hz FIG.3 - TYPICAL FORWARD CHARACTERISTICS **FIG 4. - TYPICAL JUNCTION CAPACITANCE** JUNCTION CAPACITANCE, (pF) 100 100 50 TJ = 25 °C FORWARD CURRENT, AMPERES 10 10 5 1.0 1 1 2 4 10 20 40 10 REVERSE VOLTAGE, VOLTS Pulse Width = 300 µs 2% Duty Cycle 0.1 TJ = 25 °C FIG. 5 - TYPICAL REVERSE CHARACTERISTICS 0.01 10 0 0.2 0.4 0.6 0.8 1.0 1.2 1.4 1.6 1.8 2.0 Ta = 100 °C FORWARD VOLTAGE, VOLTS REVERSE CURRENT, MICROAMPERES 1.0 0.1 Ta = 25 °C 0.01 0 20 40 60 80 10 12 140 PERCENT OF RATED REVERSE VOLTAGE, (%)

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by EIC Semiconductor manufacturer:

Other Similar products are found below :

MCL4151-TR3 MMBD3004S-13-F RD0306T-H BAV17-TR BAV19-TR 1N3611 NTE156A NTE574 NTE6244 1SS181-TP 1SS400CST2RA SDAA13 SHN2D02FUTW1T1G LS4151GS08 1N4449 1N456A 1N4934-E3/73 1N914B 1N914BTR 1SS226-TP RFUH20TB3S D291S45T BAV300-TR BAW56DWQ-7-F BAW75-TAP MM230L-CAA IDW40E65D1 JAN1N3600 JAN1N4153-1 JAN1N4454-1 JAN1N4454UR-1 LL4151-GS18 053684A SMMSD4148T3G 707803H NSVDAN222T1G CDSZC01100-HF LL4150-M-08 1N4454-TR BAV199E6433HTMA1 BAV70HDW-7 BAS28-7 JANTX1N6640 BAW56HDW-13 BAS28 TR VS-HFA04SD60STR-M3 NSVM1MA152WKT1G 1SS388-TP RGP30D-E3/73 VS-8EWF02S-M3